# International TOR Rectifier

## HFA25TB60

 $HEXFRED^{\mathsf{TM}}$ 

# Ultrafast, Soft Recovery Diode

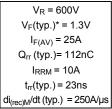
#### **Features**

- Ultrafast Recovery
- Ultrasoft Recovery
- Very Low I<sub>RRM</sub>
- · Very Low Qrr
- · Specified at Operating Conditions

#### **Benefits**

- · Reduced RFI and EMI
- Reduced Power Loss in Diode and Switching Transistor
- · Higher Frequency Operation
- · Reduced Snubbing
- · Reduced Parts Count

# 



#### Description

International Rectifier's HFA25TB60 is a state of the art ultra fast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 volts and 25 amps continuous current, the HFA25TB60 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultra fast recovery time, the HEXFRED product line features extremely low values of peak recovery current (I<sub>RRM</sub>) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA25TB60 is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.



#### **Absolute Maximum Ratings**

	Parameter	Max	Units	
V <sub>R</sub>	Cathode-to-Anode Voltage	600	V	
I <sub>F</sub> @ T <sub>C</sub> = 100°C	Continuous Forward Current	25		
I <sub>FSM</sub>	Single Pulse Forward Current	225	Α	
I <sub>FRM</sub>	Maximum Repetitive Forward Current	100		
$P_D @ T_C = 25^{\circ}C$	Maximum Power Dissipation	125	С	
P <sub>D</sub> @ T <sub>C</sub> = 100°C	Maximum Power Dissipation	50		
TJ	Operating Junction and	-55 to +150	W	
T <sub>STG</sub>	Storage Temperature Range	-55 (0 +150		

<sup>\* 125°</sup>C

International
Rectifier

Bulletin PD-2.339 rev. A 11/00

### Electrical Characteristics @ $T_J = 25$ °C (unless otherwise specified)

	Parameter	Min	Тур	Max	Units	Test Conditions	
$V_{BR}$	Cathode Anode Breakdown Voltage	600			V	I <sub>R</sub> = 100μA	
V <sub>FM</sub>	Max Forward Voltage		1.3	1.7	٧	I <sub>F</sub> = 25A	
			1.5	2.0		I <sub>F</sub> = 50A See Fig. 1	
			1.3	1.7		I <sub>F</sub> = 25A, T <sub>J</sub> = 125°C	
I <sub>RM</sub>	Max Reverse Leakage Current		1.5	20	μA	V <sub>R</sub> = V <sub>R</sub> Rated See Fig. 2	
			600	2000		T <sub>J</sub> = 125°C, V <sub>R</sub> = 0.8 x V <sub>R</sub> Rated <sub>P Rated</sub>	
C <sub>T</sub>	Junction Capacitance		55	100	pF	V <sub>R</sub> = 200V See Fig. 3	
L <sub>S</sub>	Series Inductance		8.0		nH	Measured lead to lead 5mm from	
						package body	

#### Dynamic Recovery Characteristics @ T<sub>J</sub> = 25°C (unless otherwise specified)

	Parameter	Min	Тур	Max	Units	Test Conditions		
t <sub>rr</sub>	Reverse Recovery Time		23			$I_F = 1.0A$ , $di_f/dt = 200A/\mu s$ , $V_R = 30V$		
t <sub>rr1</sub>	See Fig. 5, 6 & 16		50	75	ns	T <sub>J</sub> = 25°C		
t <sub>rr2</sub>	•		105	160		T <sub>J</sub> = 125°C	I <sub>F</sub> = 25A	
I <sub>RRM1</sub>	Peak Recovery Current		4.5	10	Α	T <sub>J</sub> = 25°C		
I <sub>RRM2</sub>	See Fig. 7& 8		8.0	15	Α .	T <sub>J</sub> = 125°C	V <sub>R</sub> = 200V	
Q <sub>rr1</sub>	Reverse Recovery Charge		112	375	nC	T <sub>J</sub> = 25°C	]	
Q <sub>rr2</sub>	See Fig. 9 & 10		420	1200	IIC	T <sub>J</sub> = 125°C	di <sub>f</sub> /dt = 200A/µs	
di <sub>(rec)M</sub> /dt1	Peak Rate of Fall of Recovery Current		250		A/µs	T <sub>J</sub> = 25°C	1	
di <sub>(rec)M</sub> /dt2	During t <sub>b</sub> See Fig. 11 & 12		160		ΑνμS	T <sub>J</sub> = 125°C		

#### **Thermal - Mechanical Characteristics**

	Parameter	Min	Тур	Max	Units
T <sub>lead</sub> ①	Lead Temperature			300	°C
RthJC	Thermal Resistance, Junction to Case			1.0	
R <sub>thJA</sub> ②	Thermal Resistance, Junction to Ambient			80	K/W
R <sub>thCS</sub> ③	Thermal Resistance, Case to Heat Sink		0.5		
Wt	Weight		2.0		g
	Weight		0.07		(oz)
	Mounting Torque	6.0		12	Kg-cm
	Woulding Forque	5.0		10	lbf•in

 $\, \oplus \,$  0.063 in. from Case (1.6mm) for 10 sec

② Typical Socket Mount

Mounting Surface, Flat, Smooth and Greased

Document Number: 93085 www.vishay.com

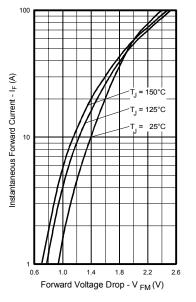


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current

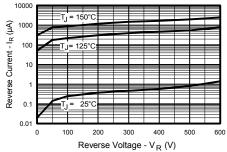
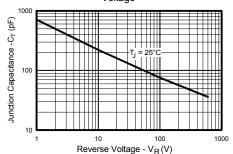


Fig. 2 - Typical Reverse Current vs. Reverse Voltage



**Fig. 3** - Typical Junction Capacitance vs. Reverse Voltage

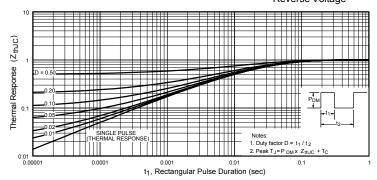


Fig. 4 - Maximum Thermal Impedance  $Z_{thjc}$  Characteristics

Bulletin PD-2.339 rev. A 11/00

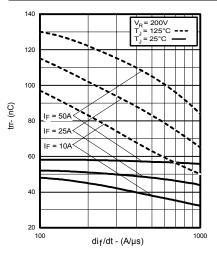
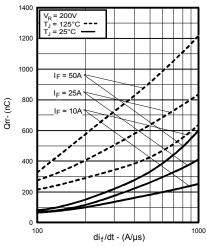


Fig. 5 - Typical Reverse Recovery vs. di<sub>f</sub>/dt

Fig. 6 - Typical Recovery Current vs. dif/dt



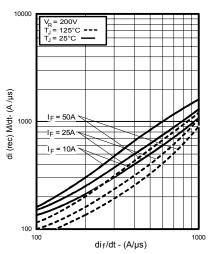


Fig. 7 - Typical Stored Charge vs. di<sub>f</sub>/dt

Fig. 8 - Typical di<sub>(rec)M</sub>/dt vs. di<sub>f</sub>/dt

Bulletin PD-2.339 rev. A 11/00

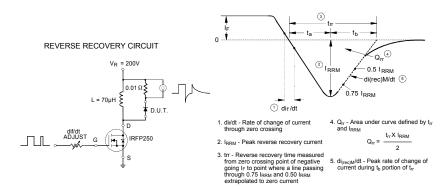
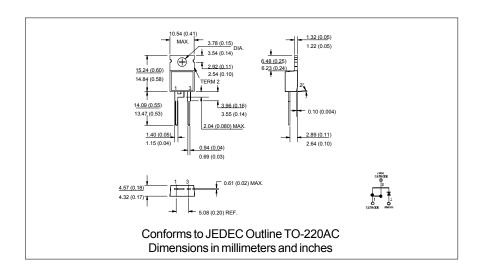


Fig. 9 - Reverse Recovery Parameter Test Circuit

Fig. 10 - Reverse Recovery Waveform and Definitions

Document Number: 93085



# International

WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245 U.S.A. Tel: (310) 322 3331. Fax: (310) 322 3332. EUROPEAN HEADQUARTERS: Hurst Green, Oxted, Surrey RH8 9BB, U.K. Tel: ++ 44 1883 732020. Fax: ++ 44 1883 733408. IR CANADA: 15 Lincoln Court, Brampton, Markham, Ontario L6T3Z2. Tel: (905) 453 2200. Fax: (905) 475 8801. IR GERMANY: Saalburgstrasse 157, 61350 Bad Homburg. Tel: ++ 49 6172 96590. Fax: ++ 49 6172 965933. IR TALY: Via Liguria 49, 10071 Borgaro, Torino. Tel: ++ 39 11 4510111, Fax: ++ 39 11 4510220. IR FAR EAST: K&H Bldg., 2F, 30-4 Nishi-Ikebukuro 3-Chome, Toshima-Ku, Tokyo, Japan 171. Tel: 813 3983 0086. IR SOUTHEAST ASIA: 1 Kim Seng Promenade, Great World City West Tower, 13-11, Singapore 23794. Tel: ++65838 4630. IR TAIWAN: 16 Fl. Suite D.207, Sec. 2, Tun Haw South Road, Talipei, 10673, Taiwan. Tel: 886 2 2377 9936.

Data and specifications subject to change without notice.



Vishay

## **Notice**

The products described herein were acquired by Vishay Intertechnology, Inc., as part of its acquisition of International Rectifier's Power Control Systems (PCS) business, which closed in April 2007. Specifications of the products displayed herein are pending review by Vishay and are subject to the terms and conditions shown below.

Specifications of the products displayed herein are subject to change without notice. Vishay Intertechnology, Inc., or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document. Except as provided in Vishay's terms and conditions of sale for such products. Vishay assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of Vishay products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Vishay for any damages resulting from such improper use or sale.

Document Number: 99901 www.vishay.com Revision: 08-Mar-07